

# NOT RECOMMENDED FOR NEW DESIGN USE DMP1007UCB9



DMP1012UCB9

### P-CHANNEL ENHANCEMENT MODE MOSFET

# **Product Summary** (Typ. @ V<sub>GS</sub> = -4.5V, T<sub>A</sub> = +25°C)

V <sub>DSS</sub>	R <sub>DS(ON)</sub>	Qg	$Q_{gd}$	I <sub>D</sub>
-8V	8.2mΩ	8.1nC	1.8nC	-10A

## **Description**

This  $3^{rd}$  generation Lateral MOSFET (LD-MOS) is engineered to minimize on-state losses and switch ultra-fast, making it ideal for high efficiency power transfer. It uses Chip-Scale Package (CSP) to increase power density by combining low thermal impedance with minimal  $R_{\text{DSiON}}$  per footprint area.

## **Applications**

- DC-DC Converters
- · Battery Management
- Load Switch

### **Features**

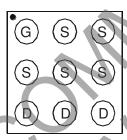
- LD-MOS Technology with the Lowest Figure of Merit:  $R_{DS(ON)} = 8.2 m\Omega$  to Minimize On-State Losses  $Q_{\alpha} = 8.1 nC$  for Ultra-Fast Switching
- V<sub>gs(th)</sub> = -0.8V Typ. for a Low Turn-On Potential
- CSP with Footprint 1.5mm x 1.5mm
- Height = 0.62mm for Low Profile
- ESD = 6kV HBM Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

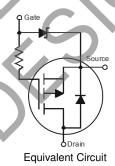
- Case: U-WLB1515-9
- Terminal Connections: See Diagram Below

### U-WLB1515-9









### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP1012UCB9-7	U-WLB1515-9	3,000/Tape & Reel

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  - See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  - 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

### U-WLB1515-9



 $\begin{array}{lll} XW = Product \ Type \ Marking \ Code \\ YM = Date \ Code \ Marking \\ Y \ or \ \overline{\underline{Y}} = Year \ (ex: B = 2014) \\ M \ or \ \overline{M} = Month \ (ex: 9 = September) \end{array}$ 

Date Code Key

Year	201	2	2013		2014	20	15	2016		2017	2	2018
Code	Z		Α		В	(	$\circ$	D		Е		F
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	-8	V	
Gate-Source Voltage		V <sub>GSS</sub>	-6	V	
Continuous Drain Current (Note 5) V <sub>GS</sub> = -4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I <sub>D</sub>	-10 -8	А
Continuous Drain Current (Note 6) $V_{GS} = -4.5V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$		I <sub>D</sub>	-7.4 -6.0	А	
Pulsed Drain Current (Pulse Duration 10µs, Duty C	ycle ≤1%)		I <sub>DM</sub>	-50	Α
Continuous Source Pin Current (Note 6)		Is	-2	Α	
Pulsed Source Pin Current (Pulse Duration 10µs, D	uty Cycle	Ism	-15	А	
Continuous Gate Current		I <sub>G</sub>	-0.5	Α	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P <sub>D</sub>	0.89	M
Total Power Dissipation (Note 6)	P <sub>D</sub>	1.57	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	+142.1	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	+80.5	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

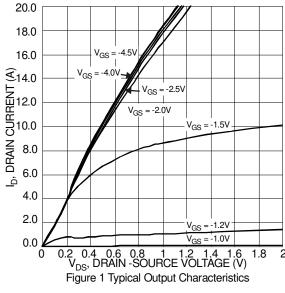
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

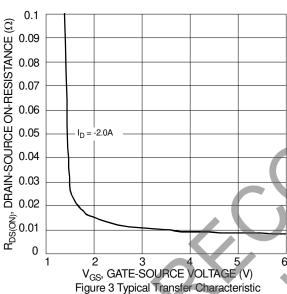
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-8	-		V	$V_{GS} = 0V, I_D = -250\mu A$
Gate to Source Voltage	$BV_{SGS}$	-6			V	$V_{DS} = 0V, I_{G} = -250\mu A$
Zero Gate Voltage Drain Current @T <sub>C</sub> = +25°C	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -4.0V, V_{GS} = 0V$
Gate-Source Leakage	Igss		+	-100	nA	$V_{GS} = -4.0V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4	-0.8	-1.1	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$
			8.2	10		$V_{GS} = -4.5V, I_D = -2A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	10	13	mΩ	$V_{GS} = -3.0V, I_D = -2A$
			11	14		$V_{GS} = -2.5V, I_D = -2A$
Forward Transfer Admittance	Y <sub>fs</sub>		16.8	_	S	$V_{DS} = -4V, I_{D} = -2A$
Diode Forward Voltage (Note 6)	$V_{SD}$		-0.7	-1	V	$V_{GS} = 0V, I_{S} = -2A$
Reverse Recovery Charge	$Q_{rr}$		6.3	_	nC	$V_{dd} = -5V, I_F = -2A,$
Reverse Recovery Time	t <sub>rr</sub>		18.5	_	ns	di/dt = 200A/µs
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C <sub>iss</sub>	_	817	1060	pF	V 4V V 0V
Output Capacitance	Coss	_	595	770	pF	$V_{DS} = -4V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	$C_{rss}$		269	350	pF	1 = 1.0ivii iz
Series Gate Resistance	R <sub>G</sub>		1.9	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge	$Q_g$		8.1	10.5	nC	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
Gate-Source Charge	Q <sub>gs</sub>		0.9	_	nC	$V_{GS} = -4.5V, V_{DS} = -4V,$ $I_{D} = -2A$
Gate-Drain Charge	$Q_{gd}$	_	1.8	_	nC	ID = -2A
Turn-On Delay Time	t <sub>D(ON)</sub>	_	6.2	10	ns	_
Turn-On Rise Time	t <sub>R</sub>	_	22.6	_	ns	$V_{DD} = -4V$ , $V_{GS} = -4.5V$ ,
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	30.1	48	ns	$I_{DS} = -2A$ , $R_G = 10\Omega$
Turn-Off Fall Time	t <sub>F</sub>	_	22.7		ns	

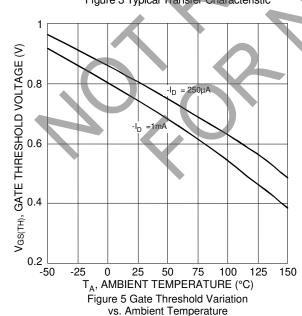
Notes:

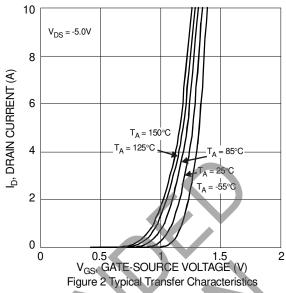
- 5. Device mounted on FR-4 PCB with minimum recommended pad layout.
- Device mounted on FR-4 material with 1-inch² (6.45cm²), 2oz (0.071mm thick) Cu.
   Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

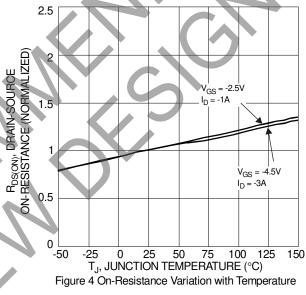
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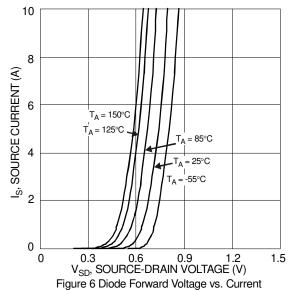




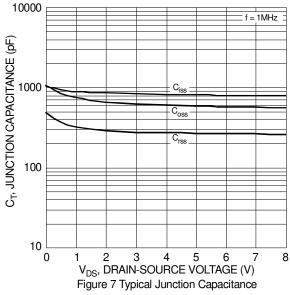


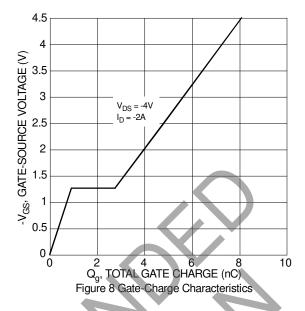


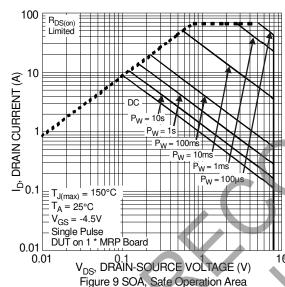


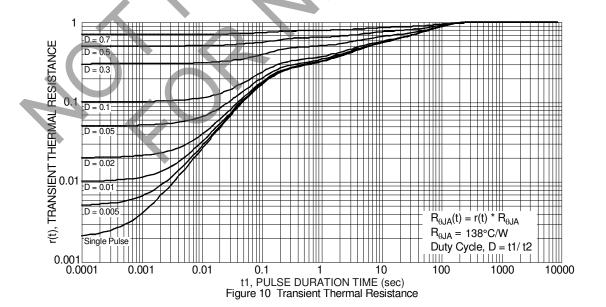














## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

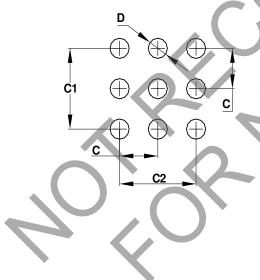
# Pin #1 ID Pin #1 ID SEATING PLANE

U-WLB1515-9							
Dim	Min	Max	Тур				
Α	-	0.62					
A2	-	0.36	0.36				
A3	0.020	0.030	0.025				
b	0.27	0.37	0.32				
D	1.47	1.50	1.49				
Е	1.47	1.50	1.49				
е			0.50				
All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)			
C	0.50			
C1	1.00			
C2	1.00			
D	0.25			



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